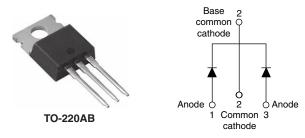


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PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 30 A				
V _R	30 V				
V_F at I_F	0.44 V				
I _{RM} max.	350 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	13 mJ				

- FEATURES
- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- RoHS COMPLIANT HALOGEN FREE
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UN							
I _{F(AV)}	Rectangular waveform (per device)	60	A				
V _{RRM}		30	V				
I _{FRM}	$T_{\rm C} = 120 \ ^{\circ}{\rm C}$ (per leg)	60	А				
I _{FSM}	t _p = 5 μs sine	1500	A				
V _F	30 A _{pk} , T _J = 125 °C	0.44	V				
TJ	Range	- 65 to 150	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-62CTQ030PbF	VS-62CTQ030-N3	UNITS		
Maximum DC reverse voltage	V _R	30	30	V		
Maximum working peak reverse voltage	V _{RWM}		30	v		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST COND	TEST CONDITIONS		UNITS		
Maximum average P	er leg	I =	50 % duty cycle at T _C = 120 °C, rectangular waveform				30	
forward current per c	device	I _{F(AV)}	30% duty cycle at $10 = 120%$	60				
Peak repetitive forward current per leg		I _{FRM}	Rated V_R , square wave, 20 kHz, T_C = 127 °C		60	А		
Maximum peak one cycle non-repetitive surge current per leg		1 =0.1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1500			
		I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	300			
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 2.9 mH		13	mJ		
			Current decaying linearly to zer Frequency limited by $T_{\rm J}$ maxim		3	А		

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VS-62CTQ030PbF, VS-62CTQ030-N3

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS		
		30 A	T _{.1} = 25 °C	0.46	0.5			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	60 A	1j=25 0	0.56	0.6	V		
	VFM (**	30 A	T 105 %O	0.39	0.44			
		60 A	T _J = 125 °C	0.54	0.59			
Maximum instantaneous reverse current	I _{RM}	$T_J = 25 \ ^{\circ}C$	Rated DC voltage	0.4	2.5	mA		
Maximum instantaneous reverse current		T _J = 125 °C	haled DC vollage	180	350			
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal rang	ge 100 kHz to 1 MHz) 25 °C	30	00	pF		
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0		nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10	000	V/µs		

Note

 $^{(1)}~$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperatur	e range	TJ		- 65 to 150	о°С		
Maximum storage temperatur	e range	T _{Stg}		- 65 to 175	U		
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	1.2	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0/11		
Approvimate weight				2	g		
Approximate weight				0.07	OZ.		
Mounting torque minimum maximum			Non-lubricated threads	6 (5)	kgf ⋅ cm		
			Non-Iubricateu tineaus	12 (10)	(lbf ⋅ in)		
Marking device			Case style TO-220AB	62CT	Q030		



VS-62CTQ030PbF, VS-62CTQ030-N3

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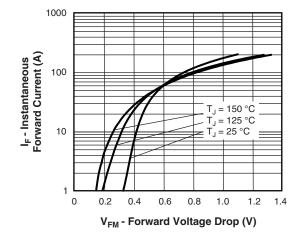


Fig. 1 - Maximum Forward Voltage Drop Characteristics

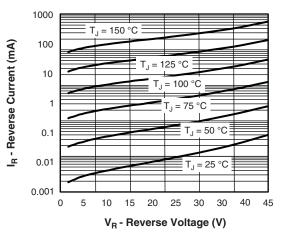


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

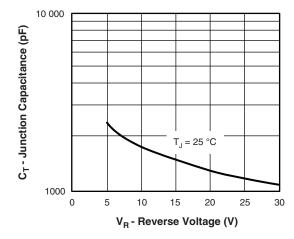
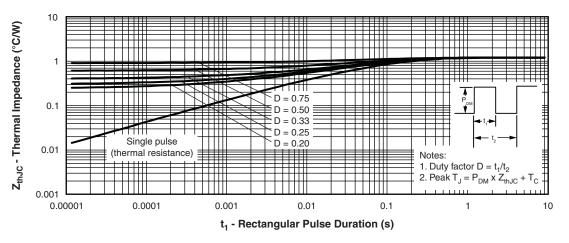


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



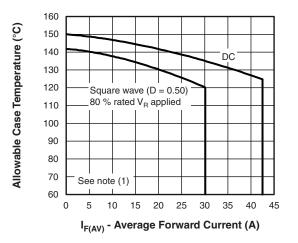


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Average Power Loss (W)

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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

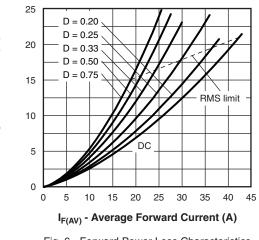


Fig. 6 - Forward Power Loss Characteristics

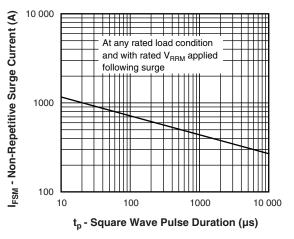


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

VS-62CTQ030PbF, VS-62CTQ030-N3



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ORDERING INFORMATION TABLE

Device code	VS-	62	С	т	Q	030	PbF
	1	2	3	4	5	6	7
1	-	Vishay	Semico	onductor	s produ	ct	
2	-	Curren	t rating	(60 = 60	A)		
3	-	- Circuit configuration					
		C = Co	mmon d	cathode			
4	-	Packag	je				
		T = TO	-220				
5	-	Schott	ky "Q" se	eries			
6	-	Voltage	e rating	(030 = 3	0 V)		
7	-	Environmental digit					
		• PbF	= Lead	(Pb)-fre	e and R	oHS co	mpliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-62CTQ030PbF	50	1000	Antistatic plastic tube				
VS-62CTQ030-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95222					
	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			
SPICE model		www.vishay.com/doc?95185			



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3 x b

3 x b2

Detail B

(b, b2)

b1. b3 Section C - C and D - D

L1 (2)

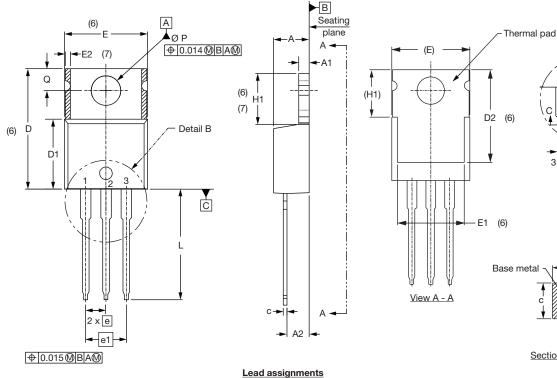
- Plating

c1 (4)

(4)

TO-220AB

DIMENSIONS in millimeters and inches



Lead tip

- **Diodes**
- 1. Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed $0.127 \text{ mm} (0.005^{\circ})$ per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	ERS INCHES		NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

(7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed

Outline conforms to JEDEC TO-220, except A2 (maximum) and (8) D2 (minimum) where dimensions are derived from the actual package outline

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